

SavantIC Semiconductor

Product Specification

Silicon PNP Power Transistors

2SB1605 2SB1605A

DESCRIPTION

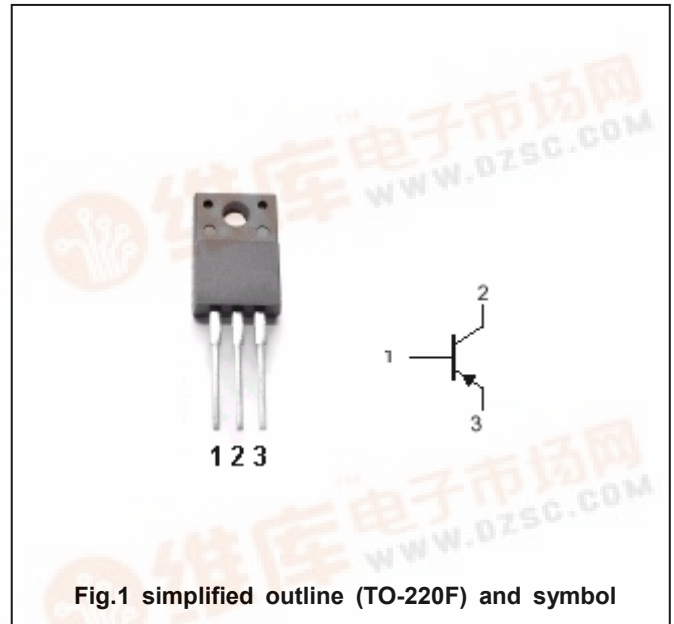
- With TO-220F package
- Low collector saturation voltage
- Good linearity of h_{FE}

APPLICATIONS

- For low-voltage switching applications

PINNING

PIN	DESCRIPTION
1	Base
2	Collector
3	Emitter



Absolute maximum ratings ($T_a=25^\circ\text{C}$)

SYMBOL	PARAMETER		CONDITIONS	MAX	UNIT
V_{CBO}	Collector-base voltage	2SB1605	Open emitter	-60	V
		2SB1605A		-80	
V_{CEO}	Collector-emitter voltage	2SB1605	Open base	-60	V
		2SB1605A		-80	
V_{EBO}	Emitter-base voltage		Open collector	-5	V
I_C	Collector current			-3	A
I_{CM}	Collector current-peak			-5	A
P_C	Collector dissipation	$T_a=25^\circ\text{C}$		2	W
		$T_C=25^\circ\text{C}$		35	
T_j	Junction temperature			150	$^\circ\text{C}$
T_{stg}	Storage temperature			-55~150	$^\circ\text{C}$

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CHARACTERISTICS

T_j=25℃ unless otherwise specified

SYMBOL	PARAMETER		CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-emitter breakdown voltage	2SB1605	I _C =-30mA ; I _B =0	-60			V
		2SB1605A		-80			
V _{CEsat}	Collector-emitter saturation voltage		I _C =-3A ; I _B =-0.375A			-1.2	V
V _{BE}	Base-emitter on voltage		I _C =-3A ; V _{CE} =-4V			-1.8	V
I _{CES}	Collector cut-off current	2SB1605	V _{CE} =-60V ; V _{BE} =0			-200	μA
		2SB1605A	V _{CE} =-80V ; V _{BE} =0				
I _{CEO}	Collector cut-off current	2SB1605	V _{CE} =-30V ; I _B =0			-300	μA
		2SB1605A	V _{CE} =-60V ; I _B =0				
I _{EBO}	Emitter cut-off current		V _{EB} =-5V ; I _C =0			-1	mA
h _{FE-1}	DC current gain		I _C =-1A ; V _{CE} =-4V	70		250	
h _{FE-2}	DC current gain		I _C =-3A ; V _{CE} =-4V	10			
f _T	Transition frequency		I _C =-0.5A ; V _{CE} =-10V		30		MHz

Switching times

t _{on}	Turn-on time	I _C =-1A ; I _{B1} =-I _{B2} =-0.1A		0.5		μs
t _{stg}	Storage time			1.2		μs
t _f	Fall time			0.3		μs

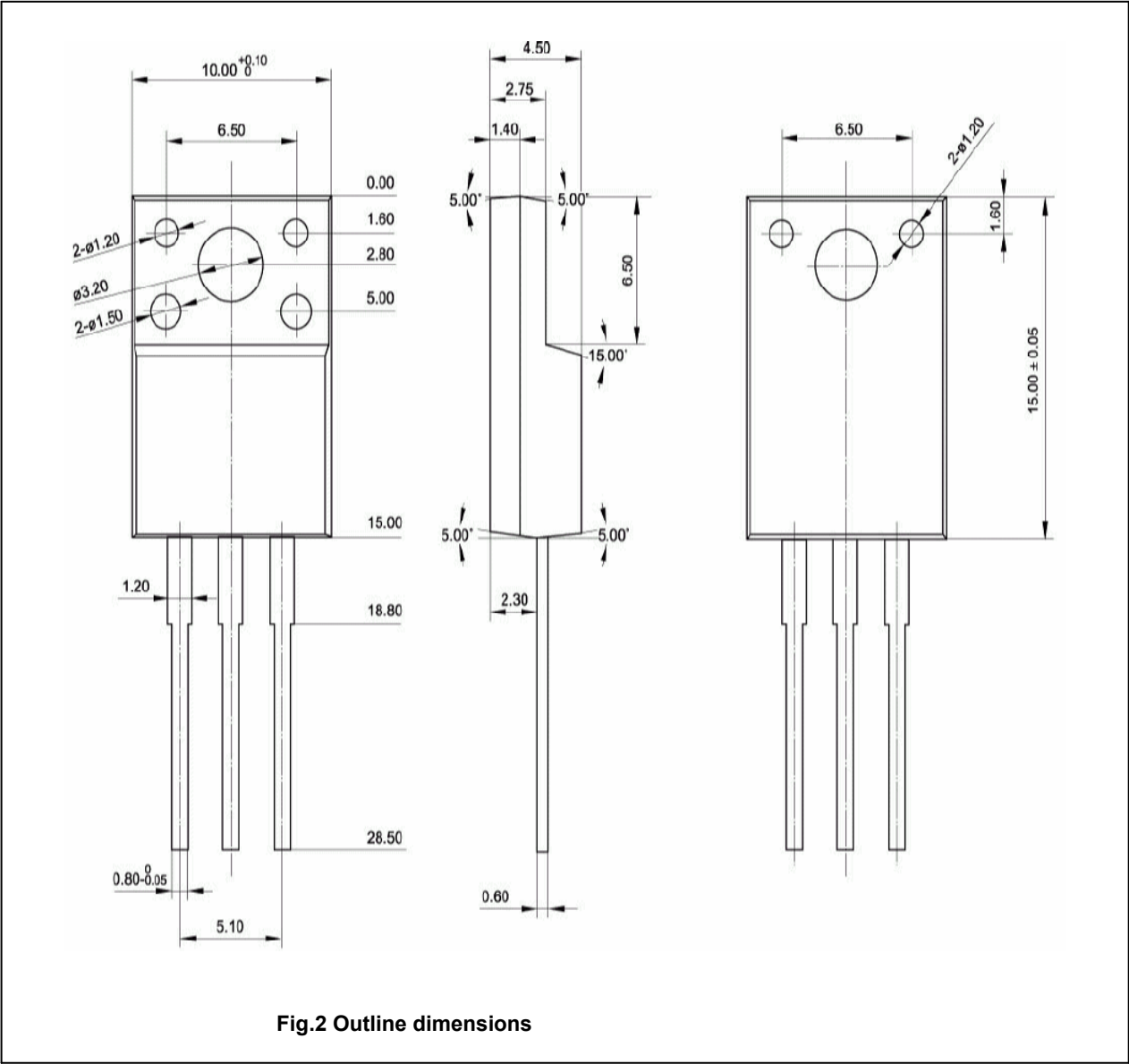
◆ h_{FE-1} Classifications

Q	P
70-150	120-250

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PACKAGE OUTLINE



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